



RoHS
COMPLIANCE



Features

- ✧ Low power loss, high efficiency
- ✧ High current capability, Low forward voltage drop.
- ✧ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✧ High surge current capability
- ✧ Qualified as per AEC-Q101
- ✧ Guard-ring for transient protection
- ✧ For use in low voltage, high frequency inverter, freewheeling, and polarity protection application
- ✧ High temperature soldering guaranteed:
260°C/10S/.375"(9.5mm) lead lengths
5 lbs tension

Mechanical Data

- ✧ Case: ITO-220AB
- ✧ Terminals: Pure tin plated leads, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ Weight: 1.7 grams
- ✧ Mounting Torque: 5 in.-lbs. max.
- ✧ Mounting position: Any

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

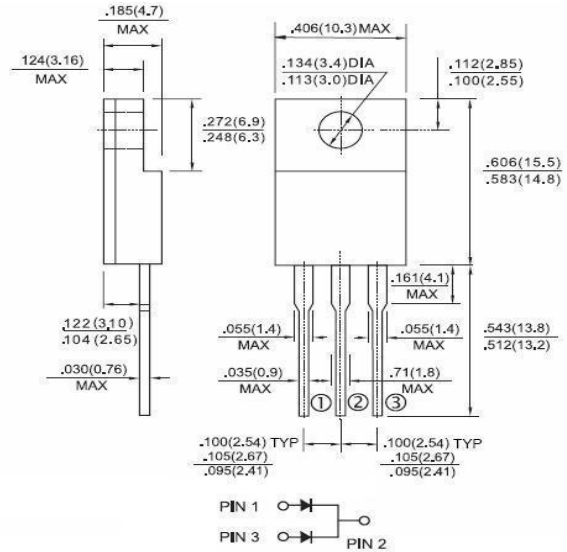
Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

MBRF10L100CT

Low VF Isolated 10.0Amp Schottky Barrier Rectifier

ITO-220AB



Dimensions in inches and (millimeters)



Marking Diagram

MBRF10LXXXCT = Specific Device Code
G = Green Compound
Y = Year Code
WW = Work Week Code

Parameter	Symbol	MBRF10L100CT		Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100		V
Maximum RMS Voltage	V_{RMS}	70		V
Maximum DC blocking voltage	V_{DC}	100		V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10		A
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	$I_{F(RMS)}$	10		A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I_{FSM}	120		A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1		A
Maximum Instantaneous Forward Voltage (Pulse test: $t_p=300\mu s$, $\delta < 1\%$) @ 5A / $T_a=25^\circ C$ @ 5A / $T_a=125^\circ C$ @ 10A / $T_a=25^\circ C$ @ 10A / $T_a=125^\circ C$	V_F	TYP. 0.73 0.59 0.82 0.66	Max. 0.76 0.65 0.85 0.71	V
Maximum Reverse Current (Pulse test: $t_p=300\mu s$, $\delta < 1\%$) $T_a=25^\circ C$ $T_a=125^\circ C$	I_R	TYP. 0.3 0.5	Max. 20 15	μA mA
Voltage rate of change (rated V_R)	dV/dt	10,000		V/ μs
Typical Junction Capacitance (Note 2)	C_j	185		pF
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	5.5		$^\circ C/W$
Operating Temperature Range	T_J	-55 to + 150		$^\circ C$
Storage Temperature Range	T_{STG}	-55 to + 150		$^\circ C$

Note1: 2.0 μs Pulse Width, F=1.0KHz, Continues 10 cycles

Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

Note3: Mount on Heatsink Size of 4" x 6" x 0.25" Al-Plate

Version:A10

RATINGS AND CHARACTERISTIC CURVES (MBRF10L100CT)

Fig.1 Maximum Forward Current Derating Curve

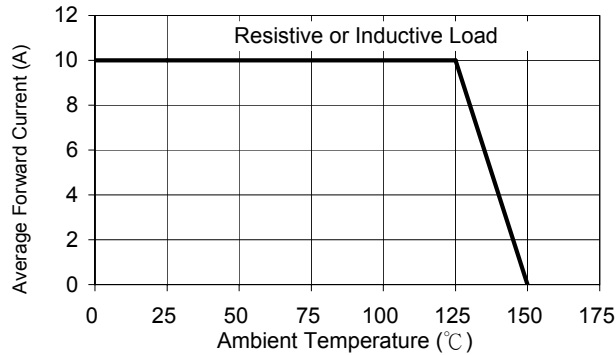


Fig. 2 Maximum Forward Surge Current

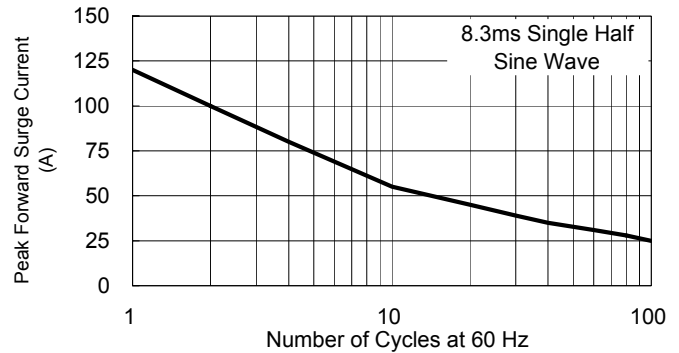


Fig. 3 Typical Forward Characteristics

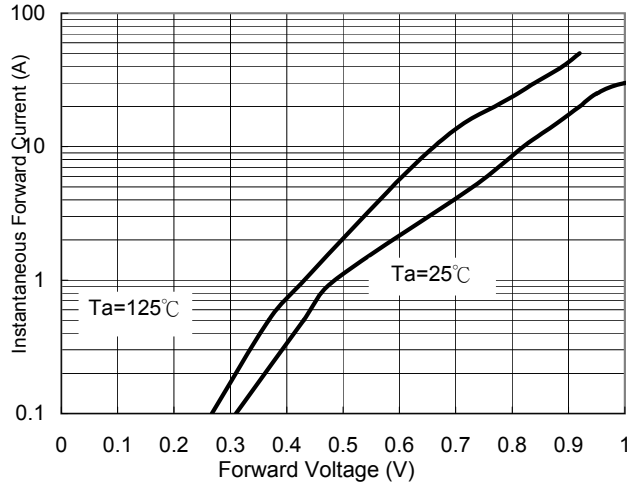


Fig. 4 Typical Reverse Characteristics

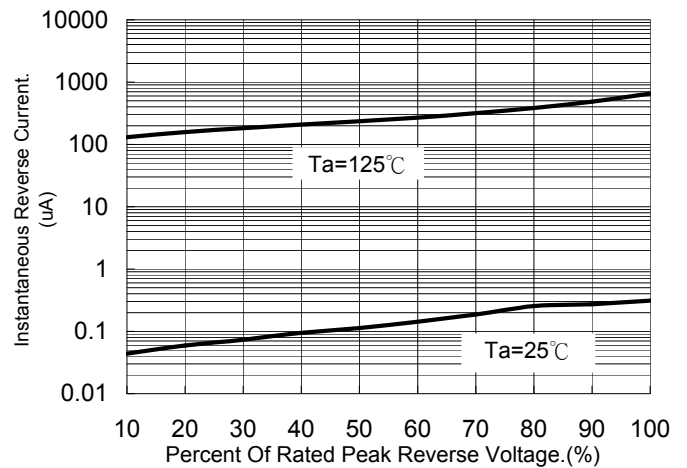


Fig. 5 Typical Junction Capacitance

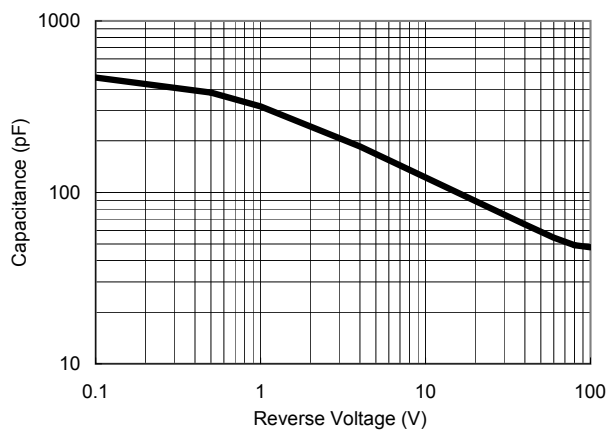


Fig. 6 Typical Transient Thermal Impedance

